## INFORMATION DISCLOSURE CITATION

(Use several sheets if necessary)

Docket	Number	(Optional)
		EU II.13

Application Number

NEW APPLICATION

Applicant(s)

Kazuo MATSUZAKI et al.

Filing Date

January 9, 2001

Group Art Unit

U.S. PATENT DOCUMENTS

				U.S. PATENT DOCUMENTS			SIA	
EXAMINER	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILMED	
	us	5,432,370	7/95	Kitamura et al.	257	339	_ <u>g</u>	
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OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

·	"Lowered on-state resistance of lateral power MOSFET with high withstand voltage for Intelligent Power Device"; Uno et al.; The Institute of Electrical Engineers of Japan, EDD-93-21, SPC-93-43; pgs. 21-29; October 7, 1993
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EXAMINER

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DATE CONSIDERED

9/20/02

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.